



60V N-CHANNEL ENHANCEMENT MODE MOSFET

100% Unclamped Inductive Switch (UIS) test in production

Case Material: Molded Plastic, "Green" Molding Compound. UL

Terminals: Matte Tin Finish annealed over Copper leadframe.

Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

Flammability Classification Rating 94V-0 (Note 1)

Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 Weight: 0.33 grams (approximate)

Terminals Connections: See Diagram

Features and Benefits

Low on-resistance Fast switching speed

Mechanical Data
 Case: TO252

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D T _A = +25°C
60V	$68m\Omega @ V_{GS} = 10V$	8.5A
	100m Ω @ V _{GS} = 4.5V	7.0A

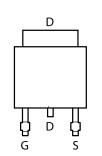
Description

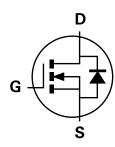
This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Transformer Driving Switch
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply







PIN OUT -TOP VIEW

Equivalent Circuit

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN6068LK3-13	N6068L	13	16	2,500

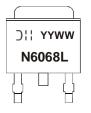
Note: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information





Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic Drain-Source voltage			Symbol	Value	Unit
			V _{DSS}	60	V
Gate-Source voltage (Note 5)		(Note 5)	V _{GS}	±20	V
Single Pulsed Avalanche Energy (Note 11)		(Note 11)	Eas	37.5	mJ
Single Pulsed Avalanche Current (Note 11)		(Note 11)	I _{AS}	5.0	А
		(Note 7)		8.5	
Continuous Drain current	$V_{GS} = 10V$	$T_{A} = 70^{\circ}C$ (Note 7)	ID	6.8	A
		(Note 6)		6.0	
Pulsed Drain current	V _{GS} = 10V	(Note 8)	IDM	22.2	A
Continuous Source current (Body diode) (Note 7)		(Note 7)	Is	10.2	А
Pulsed Source current (Body diode) (Note 8)		I _{SM}	22.2	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 6)		4.12 33	
Power dissipation Linear derating factor	(Note 7)	PD	8.49 67.9	₩ mW/°C
	(Note 9)		2.12 16.9	
	(Note 6)		30.3	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	14.7	0000
	(Note 9)		59.0	°C/W
Thermal Resistance, Junction to Lead	(Note 10)	R _{θJL}	3.09	
Operating and storage temperature range		T _J , T _{STG}	-55 to +150	°C

Notes: 5. AEC-Q101 V_{GS} maximum is $\pm 16V.$

6. For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

7. Same as note 2, except the device is measured at t \leq 10 sec.

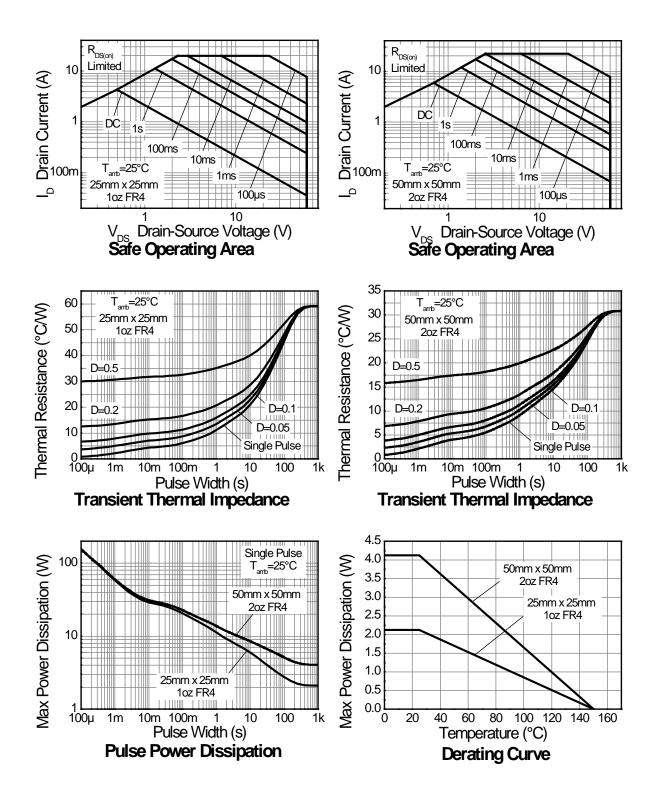
8. Same as note 2, except the device is pulsed with D = 0.02 and pulse width 300 µs. The pulse current is limited by the maximum junction temperature. 9. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

10. Thermal resistance from junction to solder-point (at the end of the drain lead).

11. UIS in production with L = 3.0mH, I_{AS} = 5.0Å, R_G = 25• , V_{DD} = 50V, starting T_J = 25°C



Thermal Characteristics





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

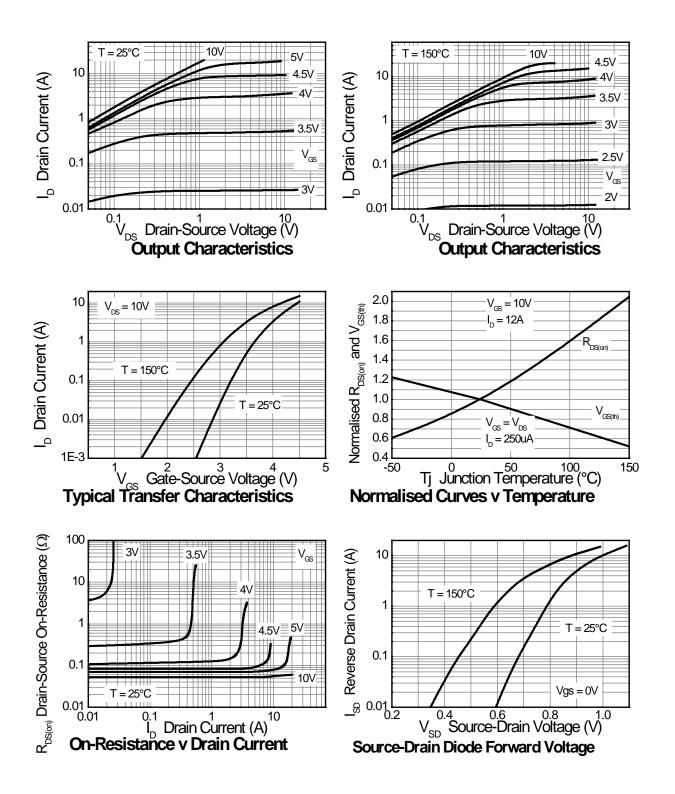
Characteristic	Symbol	Min	Тур	Max	Unit	Test	Condition
OFF CHARACTERISTICS			•	•			
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	I _D = 250μA, V _{GS} = 0V	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	0.5	μA	V_{DS} = 60V, V_{GS}	= 0V
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V _{GS} = ±20V, V _{DS} = 0V	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	1.0	_	3.0	V	I _D = 250μA, V _{DS}	s= V _{GS}
Static Drain-Source On-Resistance (Note 12)	Р			0.068	Ω	V_{GS} = 10V, I_{D} =	12A
	R _{DS (ON)}	_	_	0.100	52	V_{GS} = 4.5V, I_{D} =	6A
Forward Transconductance (Notes 12 & 13)	g fs	_	19.7	_	S	V _{DS} = 15V, I _D = 12A	
Diode Forward Voltage (Note 12)	V _{SD}	_	0.98	1.15	V	I _S = 12A, V _{GS} = 0V	
Reverse recovery time (Note 13)	t _{rr}		145	_	ns	—I _S = 12A, di/dt= 100A/μs	
Reverse recovery charge (Note 13)	Q _{rr}	_	929	_	nC		
DYNAMIC CHARACTERISTICS (Note 13)							
Input Capacitance	C _{iss}	_	502	_	pF	V _{DS} = 30V, V _{GS} = 0V f= 1MHz	
Output Capacitance	C _{oss}	_	45.7	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	27.1	_	pF		
Total Gate Charge	Qg	_	5.55	_	nC	V _{GS} = 4.5V	
Total Gate Charge	Qg	_	10.3	_	nC		V _{DS} = 30V
Gate-Source Charge	Q _{gs}	_	1.6	_	nC	V _{GS} = 10V	I _D = 12A
Gate-Drain Charge	Q _{gd}	_	3.5		nC	┨ │ │	
Turn-On Delay Time (Note 14)	t _{D(on)}	_	3.6	_	ns		
Turn-On Rise Time (Note 14)	tr	_	10.8	_	ns	V_{DD} = 30V, V_{GS} = 10V I_D = 12A, $R_G \cong 6.0\Omega$	
Turn-Off Delay Time (Note 14)	t _{D(off)}		11.9		ns		
Turn-Off Fall Time (Note 14)	t _f	_	8.7	_	ns	1	

Notes:

12. Measured under pulsed conditions. Pulse width \leq 300 μ s; duty cycle \leq 2% 13. For design aid only, not subject to production testing. 14. Switching characteristics are independent of operating junction temperatures.

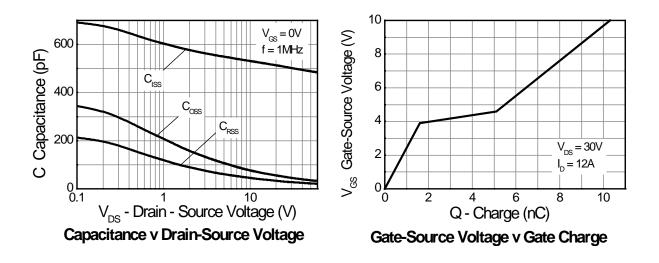


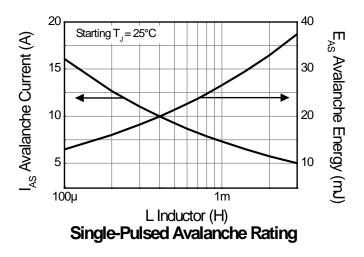
Typical Characteristics





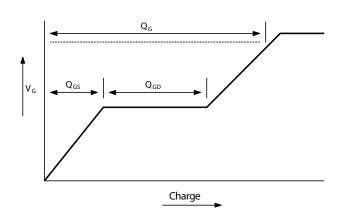
Typical Characteristics - continued



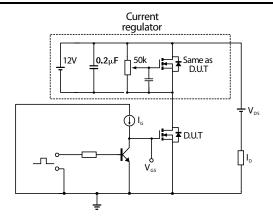




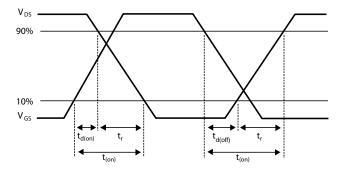
Test Circuits



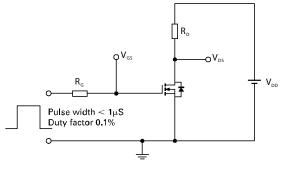
Basic gate charge waveform







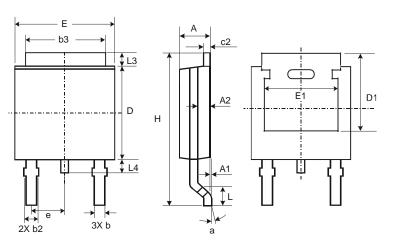
Switching time waveforms



Switching time test circuit

Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

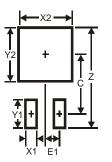


TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: DMN6068LK3-13